

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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## 2SK3150(L), 2SK3150(S)

Silicon N Channel MOS FET  
High Speed Power Switching

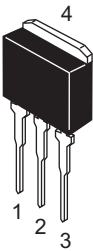
REJ03G1075-0400  
(Previous: ADE-208-750B)  
Rev.4.00  
Sep 07, 2005

### Features

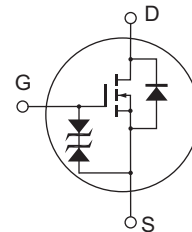
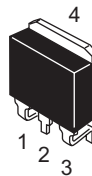
- Low on-resistance  
 $R_{DS} = 45 \text{ m}\Omega$  typ.
- High speed switching
- 4 V gate drive device can be driven from 5 V source

### Outline

RENESAS Package code: PRSS0004AE-A  
(Package name: LDKPAK(L))



RENESAS Package code: PRSS0004AE-B  
(Package name: LDKPAK(S)-(1))



1. Gate
2. Drain
3. Source
4. Drain

## Absolute Maximum Ratings

(Ta = 25°C)

| Item                                   | Symbol                          | Ratings     | Unit |
|--|---------------------------------|-------------|------|
| Drain to source voltage                | $V_{DSS}$                       | 100         | V    |
| Gate to source voltage                 | $V_{GSS}$                       | ±20         | V    |
| Drain current                          | $I_D$                           | 20          | A    |
| Drain peak current                     | $I_{D(pulse)}$ <sup>Note1</sup> | 80          | A    |
| Body-drain diode reverse drain current | $I_{DR}$                        | 20          | A    |
| Avalanche current                      | $I_{AP}$ <sup>Note3</sup>       | 20          | A    |
| Avalanche energy                       | $E_{AR}$ <sup>Note3</sup>       | 40          | mJ   |
| Channel dissipation                    | $P_{ch}$ <sup>Note2</sup>       | 50          | W    |
| Channel temperature                    | Tch                             | 150         | °C   |
| Storage temperature                    | Tstg                            | -55 to +150 | °C   |

- Notes: 1.  $PW \leq 10\mu s$ , duty cycle  $\leq 1\%$   
 2. Value at  $T_c = 25^\circ C$   
 3. Value at  $T_{ch} = 25^\circ C$ ,  $R_g \geq 50 \Omega$

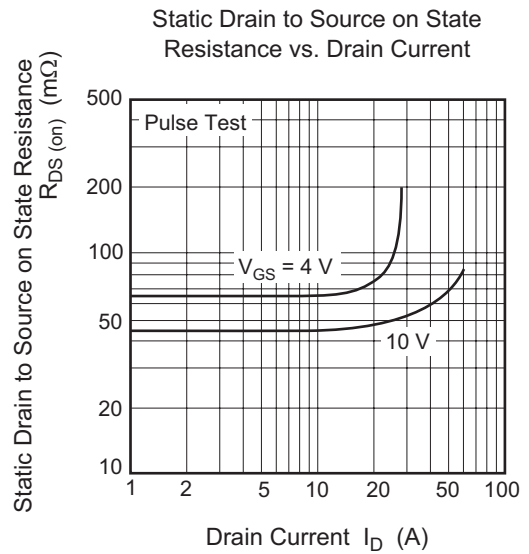
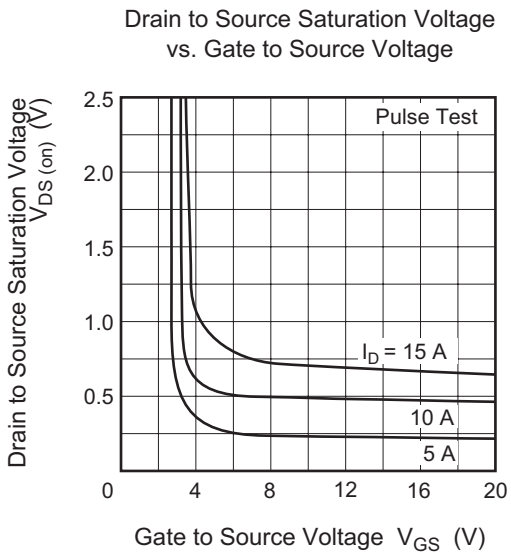
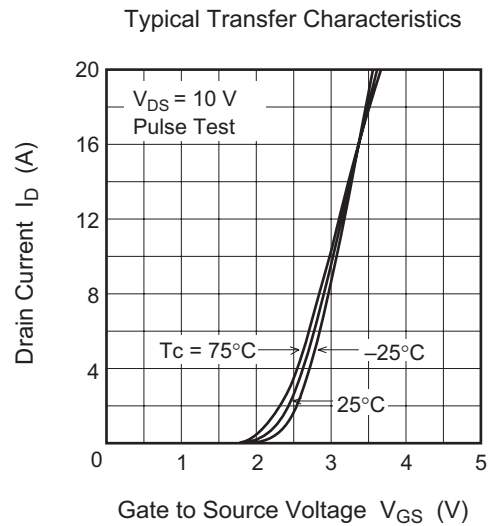
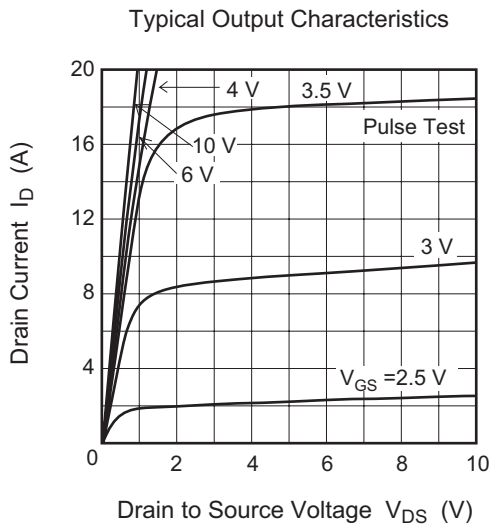
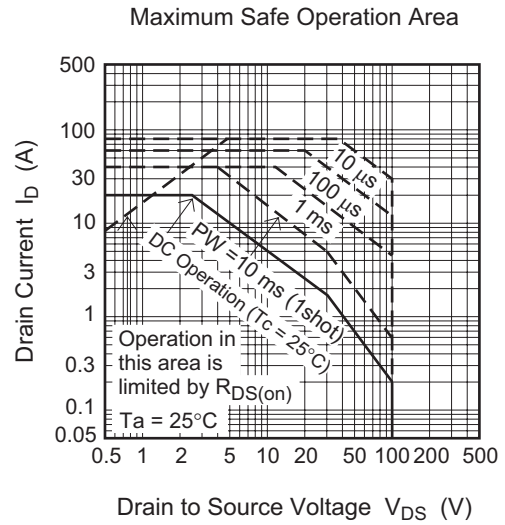
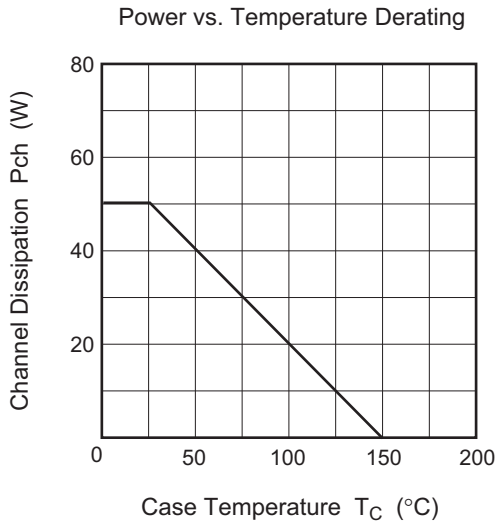
## Electrical Characteristics

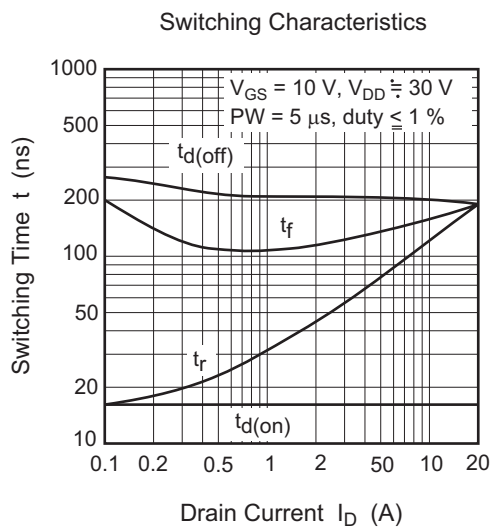
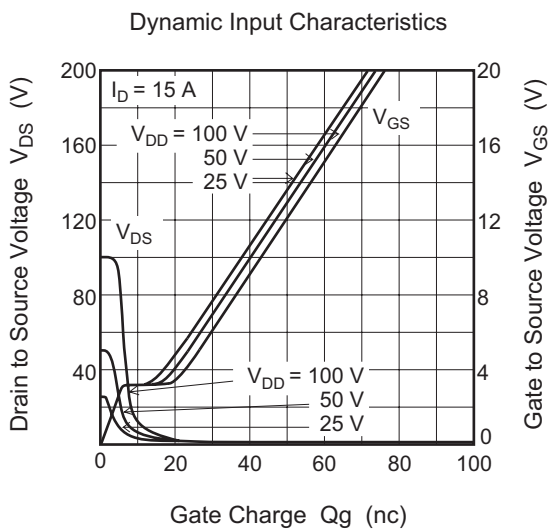
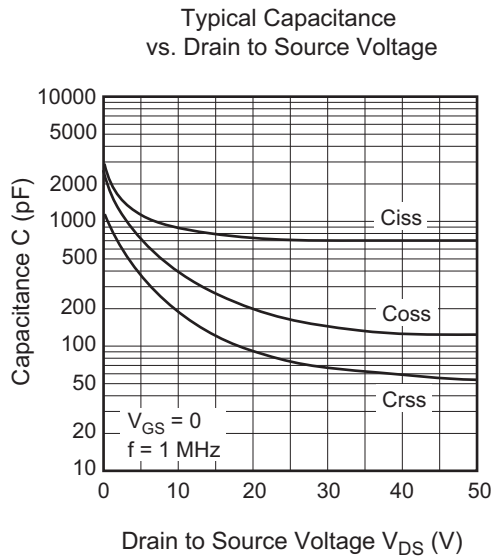
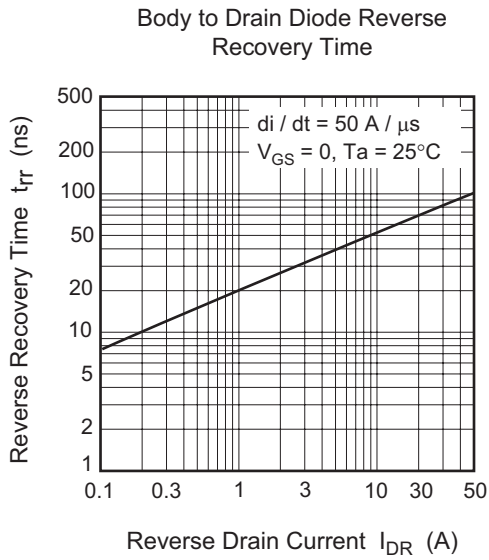
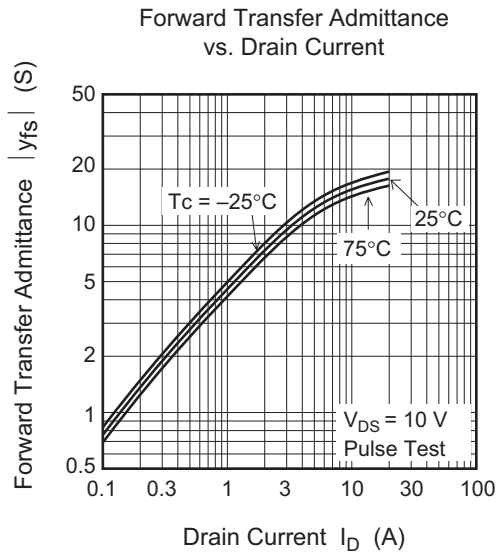
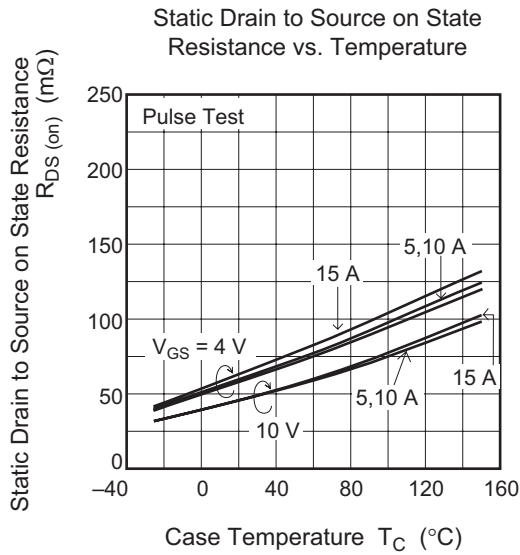
(Ta = 25°C)

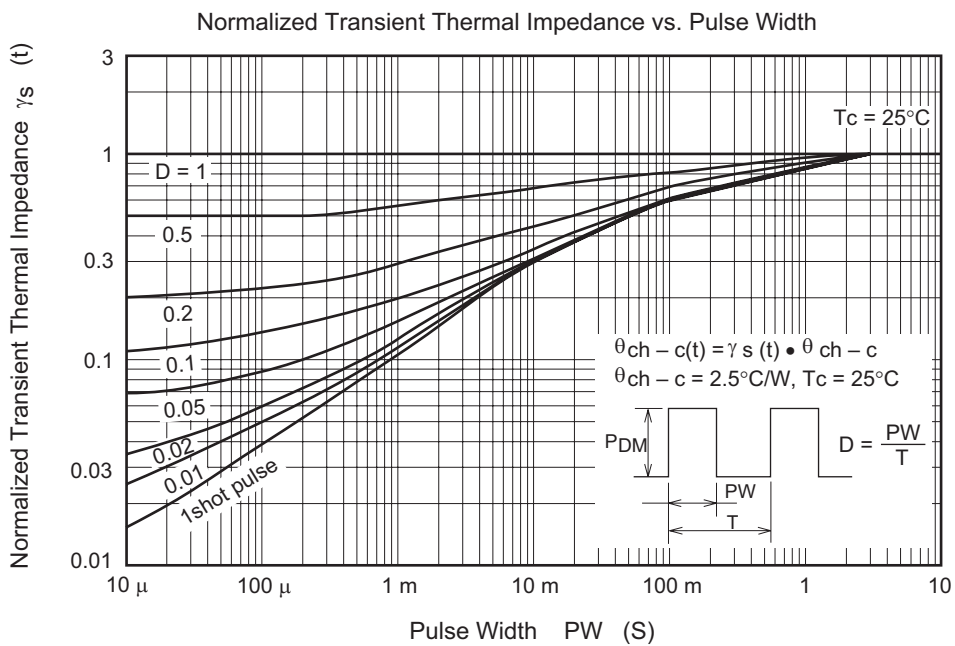
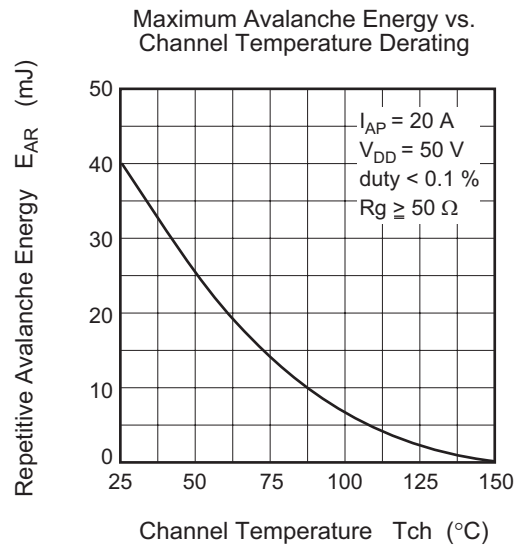
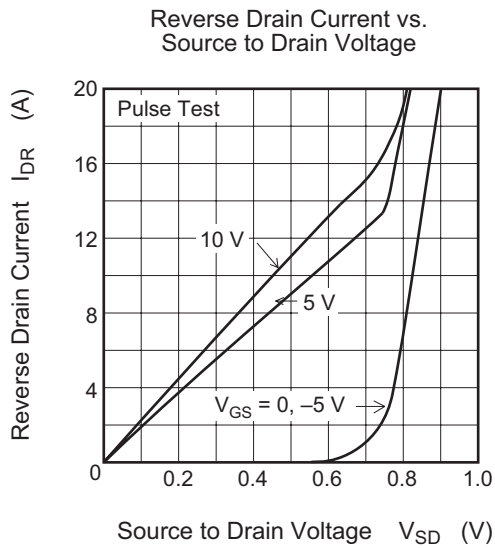
| Item                                       | Symbol        | Min | Typ | Max | Unit | Test Conditions   |
|--|---------------|-----|-----|-----|------|---|
| Drain to source breakdown voltage          | $V_{(BR)DSS}$ | 100 | —   | —   | V    | $I_D = 10 \text{ mA}$ , $V_{GS} = 0$                                  |
| Gate to source breakdown voltage           | $V_{(BR)GSS}$ | ±20 | —   | —   | V    | $I_G = \pm 100 \mu A$ , $V_{DS} = 0$                                  |
| Gate to source leak current                | $I_{GSS}$     | —   | —   | ±10 | μA   | $V_{GS} = \pm 16 \text{ V}$ , $V_{DS} = 0$                            |
| Zero gate voltage drain current            | $I_{DSS}$     | —   | —   | 10  | μA   | $V_{DS} = 100 \text{ V}$ , $V_{GS} = 0$                               |
| Gate to source cutoff voltage              | $V_{GS(off)}$ | 1.0 | —   | 2.5 | V    | $I_D = 1 \text{ mA}$ , $V_{DS} = 10 \text{ V}$                        |
| Static drain to source on state resistance | $R_{DS(on)}$  | —   | 45  | 60  | mΩ   | $I_D = 10 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note4</sup>       |
|  | $R_{DS(on)}$  | —   | 65  | 85  | mΩ   | $I_D = 10 \text{ A}$ , $V_{GS} = 4 \text{ V}$ <sup>Note4</sup>        |
| Forward transfer admittance                | $ y_{fs} $    | 8.5 | 14  | —   | S    | $I_D = 10 \text{ A}$ , $V_{DS} = 10 \text{ V}$ <sup>Note4</sup>       |
| Input capacitance                          | $C_{iss}$     | —   | 900 | —   | pF   | $V_{DS} = 10 \text{ V}$ , $V_{GS} = 0$ ,<br>$f = 1 \text{ MHz}$       |
| Output capacitance                         | $C_{oss}$     | —   | 400 | —   | pF   |   |
| Reverse transfer capacitance               | $C_{rss}$     | —   | 210 | —   | pF   |   |
| Turn-on delay time                         | $t_{d(on)}$   | —   | 15  | —   | ns   | $I_D = 10 \text{ A}$ , $V_{GS} = 10 \text{ V}$ ,<br>$R_L = 3 \Omega$  |
| Rise time                                  | $t_r$         | —   | 120 | —   | ns   |   |
| Turn-off delay time                        | $t_{d(off)}$  | —   | 200 | —   | ns   |   |
| Fall time                                  | $t_f$         | —   | 150 | —   | ns   |   |
| Body-drain diode forward voltage           | $V_{DF}$      | —   | 0.9 | —   | V    | $I_F = 20 \text{ A}$ , $V_{GS} = 0$                                   |
| Body-drain diode reverse recovery time     | $t_{rr}$      | —   | 90  | —   | ns   | $I_F = 20 \text{ A}$ , $V_{GS} = 0$<br>$di_F/dt = 50 \text{ A}/\mu s$ |

- Note: 4. Pulse test

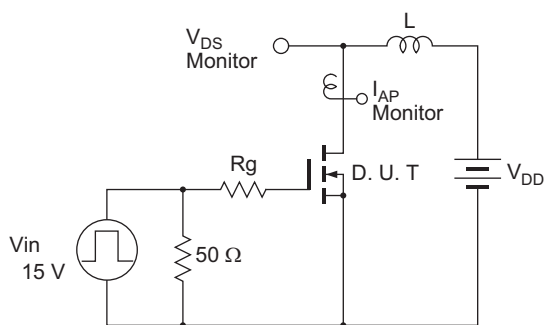
Main Characteristics



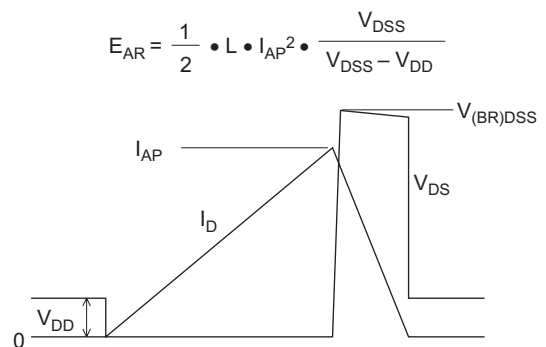


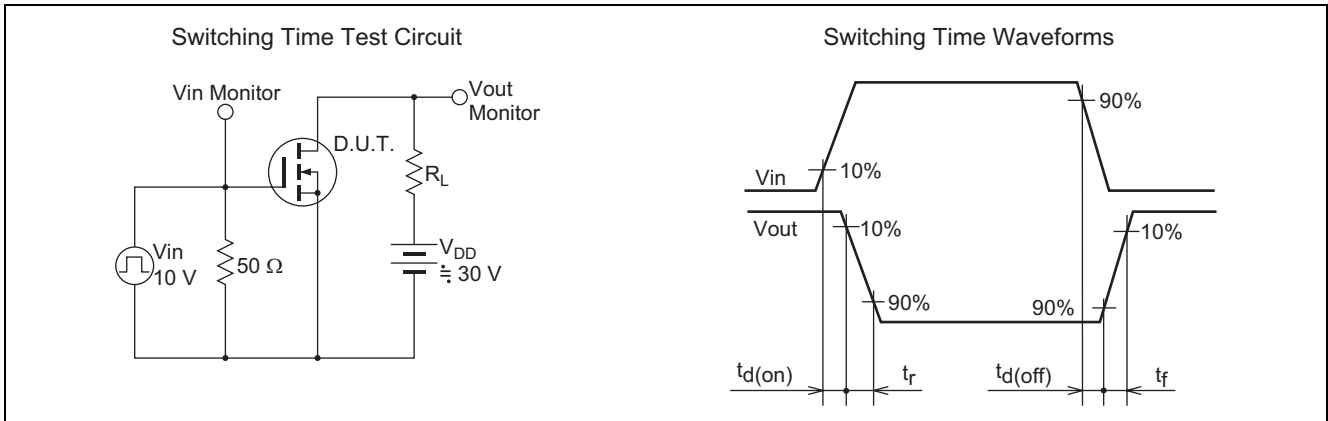


Avalanche Test Circuit



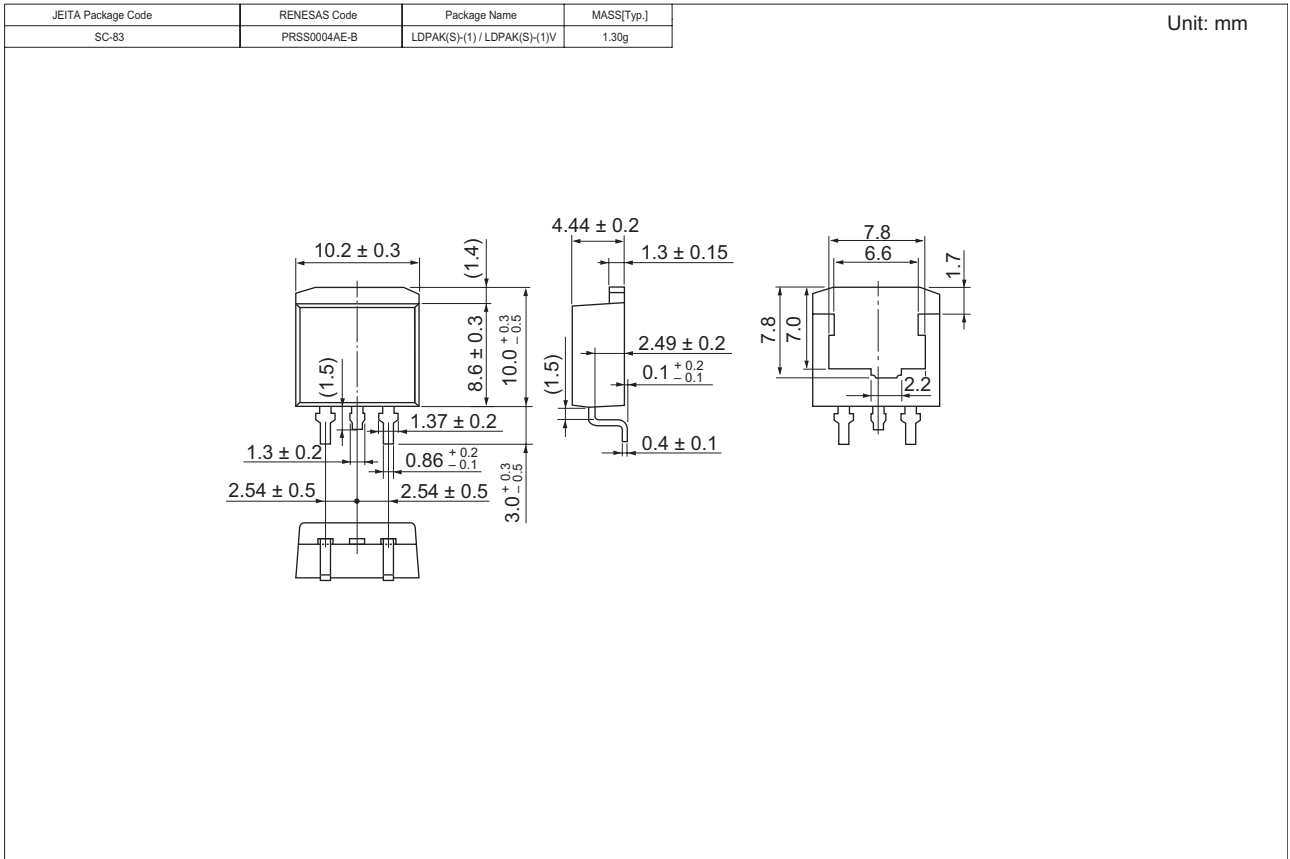
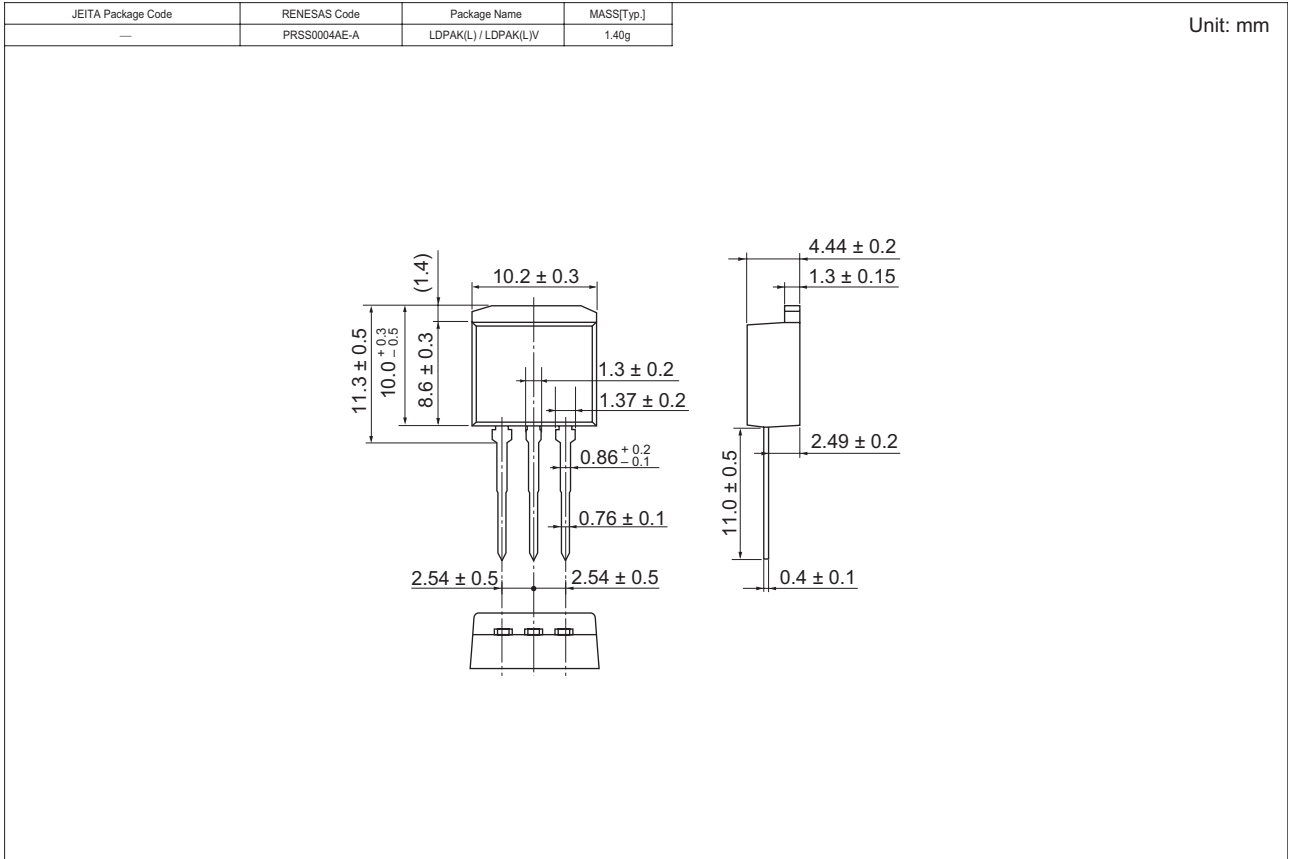
Avalanche Waveform







Package Dimensions



### Ordering Information

| Part Name    | Quantity | Shipping Container |
|--------------|----------|--------------------|
| 2SK3150L-E   | 500 pcs  | Box (Sack)         |
| 2SK3150STL-E | 1000 pcs | Taping             |

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